# **SB80W06T**

# Schottky Barrier Diode 60V, 8A, Low IR, Monolithic Dual TP Common Cathode



• High frequency rectification (switching regulators, converters, choppers)

# Features

- Low forward voltage (VF max=0.6V)
- Fast reverse recovery time
- High reliability due to highly reliable planar structure

Low switching noise Halogen free compliance

# **Specifications**

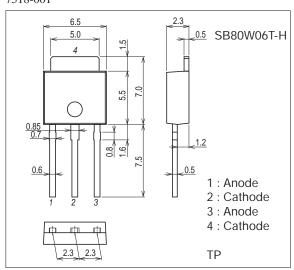
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		60	V
Nonrepetitive Peak Reverse Surge Voltage	V <sub>RSM</sub>		66	V
			Continued on	next page.

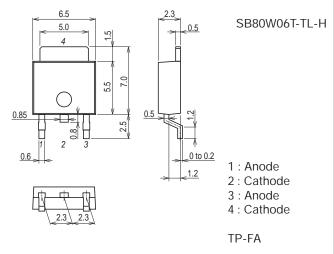
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# Package Dimensions

unit : mm (typ) 7518-001



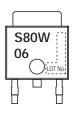
Package Dimensions unit : mm (typ) 7003-002



#### Product & Package Information

- Package : TP
- JEITA, JEDEC : SC-64, TO-251, SOT-553, DPAK
- Minimum Packing Quantity : 500 pcs./bag





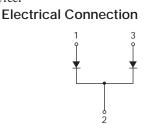


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• JEITA, JEDEC : SC-63, TO-252, SOT-428, DPAK

Minimum Packing Quantity : 700 pcs./reel

Packing Type (TP-FA) : TL





#### Continued from preceding page.

Parameter	Parameter Symbol		Ratings	Unit
Average Output Current	I0*2	50Hz resistive load, sine wave Tc=130°C	4	А
Average Output Current	I <sub>O</sub> *1	50Hz resistive load, sine wave Tc=83°C	8	А
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	40	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Note) \*1. Indicates the total value

\*2. Value per element

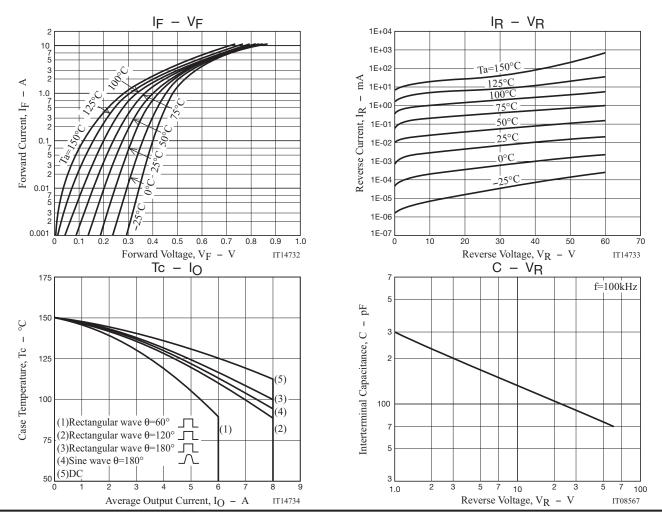
#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol Conditions		min	typ	max	Unit	
Reverse Voltage	VR	I <sub>R</sub> =1mA, Tj=25°C *2	60			V	
Forward Voltage	VF	IF=3.0A, Tj=25°C *2			0.6	V	
Reverse Current	IR	V <sub>R</sub> =30V, Tj=25°C *2			0.1	mA	
Interterminal Capacitance	С	VR=10V, Tj=25°C *2		130		pF	
Transient Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC		6		°C / W	

Note) \*2. Value per element

#### **Ordering Information**

Device	Package	Shipping	memo
SB80W06T-H	TP	500pcs./bag	Dh Free and Helegen Free
SB80W06T-TL-H	TP-FA	700pcs./reel	Pb Free and Halogen Free



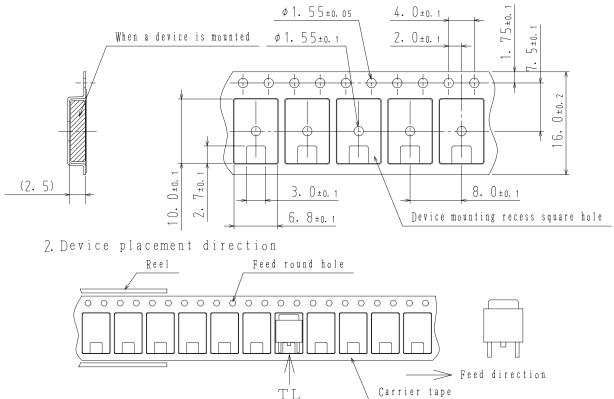
### Taping Specification SB80W06T-TL-H

Packing Format

Package Name	ckage Name Carrier Tape Maximum N devices con				Packing format	
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1) Outer BOX (A-7)	
TP-FA	ΤP	700	2, 100	12,600	) 3 reels contained 6 inner boxes contained	
	_				Dimensions:mm (external) Dimensions:mm (external)	
					183×72×185 440×195×210	
Packing met	<u>Packing method</u> <u>Reel label, Inner box label</u> (unit:mm) <u>69</u> <u>Outer box label</u> It is a label at the time of factory shipme The form of a label may change in physical distribution process. <u>108</u>					
	Type LOT Quan Orig	No. tity		TYPE O O O   II IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII	→	
	∖ Reel la	bel	Th	e LEAD FI	FREE 兼 description shows that the surface of the terminal is lead free. 1 JEITA Phase	
				LEAD FRE		
				LEAD FRE	REE 4 JEITA Phase 3	

# Taping configuration

1. Carrier tape size (unit:mm)



Those with one electrode terminal on the feed hole side ..... TL

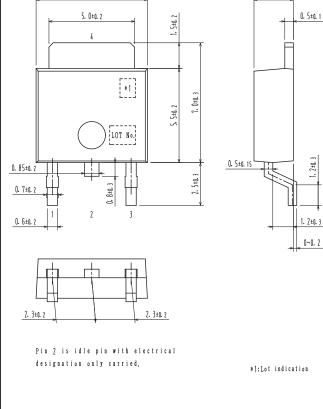
# Outline Drawing SB80W06T-TL-H

#### Mass (g) Unit Unit: mm 0.282 \* For reference mm 7.0 K 6. 5±0. 2 2. 3±0. 2 1. 5±0. 2 0. 5±0. 1 7.0 [\*1] 2.0 15 7. 0±0. 3 5. 5±0. 2 2.5

Land Pattern Example

2.3

2.3



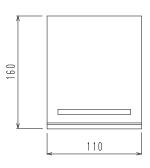
### Bag Packing Specification SB80W06T-H

<u>1. Packing Format</u>

Package Name		Maximum Numbe	r of devices cont	ained (pcs)	
I dougso Hamo	Bag	Inner box	() uter box		
TP		B-1	A-1	A-2	
	F 500 10,000		50,000	30,000	
		Packing format (Dimensions:mm (external))			
		Inner box	Outer	b o x	
		B-1		A-2	
4		4 4 5 × 2 2 5 × 5 5	470×250×300	470×250×190	

<u>2. Bag dimensions</u>





# <u>4. Outer box label</u>

(unit:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process.

3. Bag	label, [nner	b o x	label
	(unit:mm)		

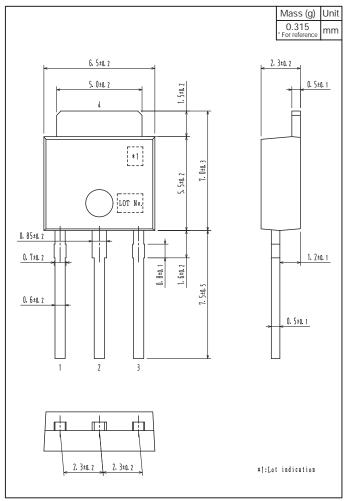
	69	
Turo No	(P) TYPE 000000000	
Type No. → LOT No. →	(P) TYPE 000000000 	
Quantity ->	(Q) QTY O, OOO (1) LEAD FREE *	4 J
Origin ->	(2) \$PECIAL 	V

NOTE (1) The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label			JEITA Phase
LEAD	FREE	3	JEITA Phase 3A
LEAD	FREE	4	JEITA Phase 3

Â	TYPE CODE	*000000000000000*
	TYPE	000000000
	QTY	0, 000 pcs (1) Lead free #
8	LOT	00000000
	PACKAGE	00000000
	SPECIAL ASSEMBLY:	*20722005310C* **** (DIFFUSION:****)
	-	108
Γ	•	-

# Outline Drawing SB80W06T-H



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